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Product Termination Notification



Product Group: SIL/Wednesday May 20, 2026/PTN-SIL-036-2026-REV-0

Conversion to Copper (Cu) Wire – SQ4949EY

For further information, please contact your regional Vishay office.

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Description of Change: The affected part number listed in this notification will be converted from gold (Au) bond wire to a copper (Cu) wire material set. The new ordering code is SQ4949CEY-T1_GE3 which has identical silicon technology and silicon die design as SQ4949EY. Small changes to the data sheet AC parameters are a consequence of lot to lot variation and/or updated characterization methods (reference: SQ4949EY Doc # 61661 Rev. A). Device performance in the application will not be impacted. There will be no change to the wafer fab location.

Reason for Change: Standardization of materials

Expected Influence on Quality/Reliability/Performance: None

Part Numbers/Series/Families Affected: SQ4949EY-T1_GE3, SQ4949EY-T1_BE3,

Vishay Brand(S): Vishay Siliconix

Time Schedule:

Last Time Buy Date: Monday November 16, 2026

Last Time Ship Date: Saturday May 15, 2027

Sample Availability: Qualified samples of replacement product are available on request.

Product Identification: SQ4949CEY-T1_GE3

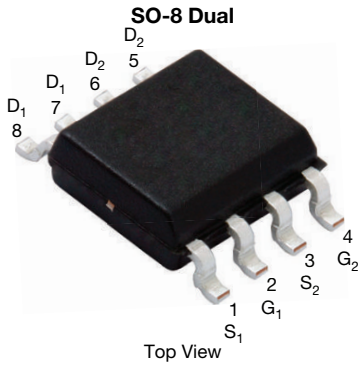
Qualification Data: AEC Q101 qualification data of replacement product is available. Qualification PPAP is available on request.

This PTN is considered approved, without further notification, unless we receive specific customer concerns before Saturday June 13, 2026 or as specified by contract.

Issued By: Lance Gurrola, automostechsupport@vishay.com



Automotive Dual P-Channel 30 V (D-S) 175 °C MOSFET

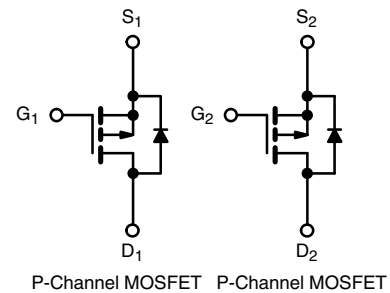


FEATURES

- TrenchFET® Power MOSFET
- 100 % R_g and UIS tested
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS COMPLIANT HALOGEN FREE



PRODUCT SUMMARY	
V _{DS} (V)	-30
R _{DS(on)} (Ω) at V _{GS} = - 10 V	0.035
R _{DS(on)} (Ω) at V _{GS} = - 4.5 V	0.065
I _D (A) per leg	-7.5
Configuration	Dual

ORDERING INFORMATION	
Package	SO-8
Lead (Pb)-free and halogen-free	SQ4949CEY (for detailed order number please see www.vishay.com/doc?79771)

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)			
PARAMETER	SYMBOL	LIMIT	UNIT
Drain-source voltage	V _{DS}	-30	V
Gate-source voltage	V _{GS}	± 20	
Continuous drain current	I _D	T _C = 25 °C	-7.5
		T _C = 125 °C	-4.3
Continuous source current (diode conduction)	I _S	-3	A
Pulsed drain current ^a	I _{DM}	-30	
Single pulse avalanche current	I _{AS}	-17	
Single pulse avalanche energy	E _{AS}	14	mJ
Maximum power dissipation	P _D	T _C = 25 °C	3.3
		T _C = 125 °C	1.1
Operating junction and storage temperature range	T _J , T _{stg}	-55 to +175	°C

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-ambient	R _{thJA}	110	°C/W
Junction-to-foot (drain)	R _{thJF}	45	

Notes

- Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %
- When mounted on 1" square PCB (FR-4 material)



SPECIFICATIONS ($T_C = 25\text{ }^\circ\text{C}$, unless otherwise noted)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V_{DS}	$V_{GS} = 0\text{ V}$, $I_D = -250\text{ }\mu\text{A}$		-30	-	-	V
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250\text{ }\mu\text{A}$		-1.5	-2.0	-2.5	
Gate-source leakage	I_{GSS}	$V_{DS} = 0\text{ V}$, $V_{GS} = \pm 20\text{ V}$		-	-	± 100	nA
Zero gate voltage drain current	I_{DSS}	$V_{GS} = 0\text{ V}$	$V_{DS} = -30\text{ V}$	-	-	-1.0	μA
		$V_{GS} = 0\text{ V}$	$V_{DS} = -30\text{ V}$, $T_J = 125\text{ }^\circ\text{C}$	-	-	-50	
		$V_{GS} = 0\text{ V}$	$V_{DS} = -30\text{ V}$, $T_J = 175\text{ }^\circ\text{C}$	-	-	-150	
On-state drain current ^a	$I_{D(on)}$	$V_{GS} = -10\text{ V}$	$V_{DS} \leq -5\text{ V}$	-20	-	-	A
Drain-source on-state resistance ^a	$R_{DS(on)}$	$V_{GS} = -10\text{ V}$	$I_D = -5.9\text{ A}$	-	0.027	0.035	Ω
		$V_{GS} = -10\text{ V}$	$I_D = -5.9\text{ A}$, $T_J = 125\text{ }^\circ\text{C}$	-	-	0.051	
		$V_{GS} = -10\text{ V}$	$I_D = -5.9\text{ A}$, $T_J = 175\text{ }^\circ\text{C}$	-	-	0.060	
		$V_{GS} = -4.5\text{ V}$	$I_D = -4\text{ A}$	-	0.051	0.065	
Forward transconductance ^b	g_{fs}	$V_{DS} = -15\text{ V}$, $I_D = -5.9\text{ A}$		-	12	-	S
Dynamic ^b							
Input capacitance	C_{iss}	$V_{GS} = 0\text{ V}$	$V_{DS} = -25\text{ V}$, $f = 1\text{ MHz}$	-	835	1020	pF
Output capacitance	C_{oss}			-	158	210	
Reverse transfer capacitance	C_{rss}			-	102	145	
Total gate charge ^c	Q_g	$V_{GS} = -10\text{ V}$	$V_{DS} = -15\text{ V}$, $I_D = -4.9\text{ A}$	-	18.6	30	nC
Gate-source charge ^c	Q_{gs}			-	3.3	-	
Gate-drain charge ^c	Q_{gd}			-	4.4	-	
Gate resistance	R_g	f = 1 MHz		3.2	6.5	12	Ω
Turn-on delay time ^c	$t_{d(on)}$	$V_{DD} = -15\text{ V}$, $R_L = 15\text{ }\Omega$ $I_D \equiv -1\text{ A}$, $V_{GEN} = -10\text{ V}$, $R_g = 1\text{ }\Omega$		-	9	11	ns
Rise time ^c	t_r			-	5	14	
Turn-off delay time ^c	$t_{d(off)}$			-	29	42	
Fall time ^c	t_f			-	6	12	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed current ^a	I_{SM}			-	-	-30	A
Forward voltage	V_{SD}	$I_F = -5\text{ A}$, $V_{GS} = 0\text{ V}$		-	-0.85	-1.2	V

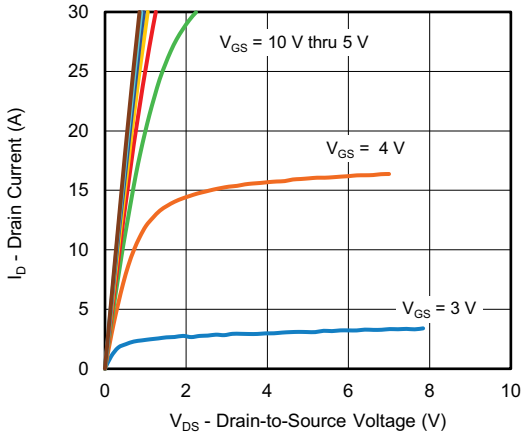
Notes

- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$
b. Guaranteed by design, not subject to production testing
c. Independent of operating temperature

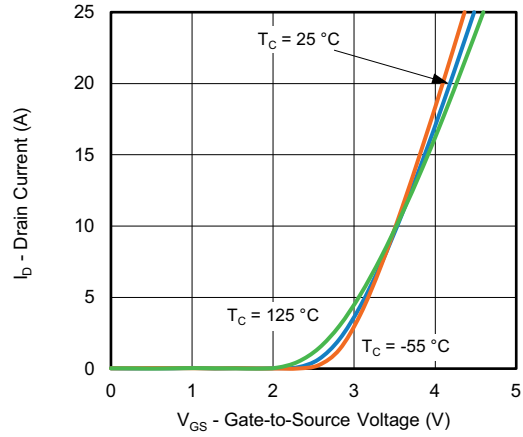
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



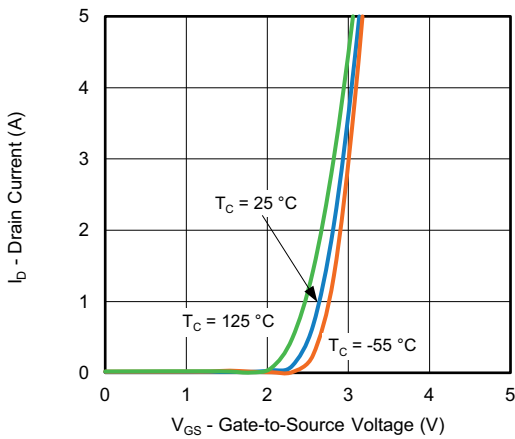
TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



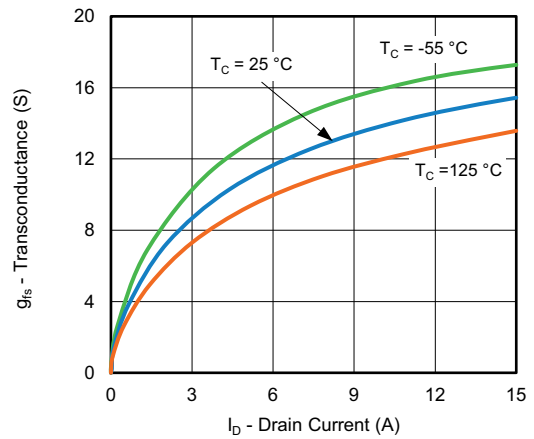
Output Characteristics



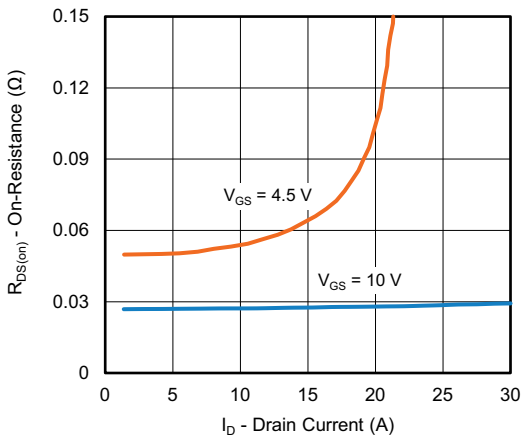
Transfer Characteristics



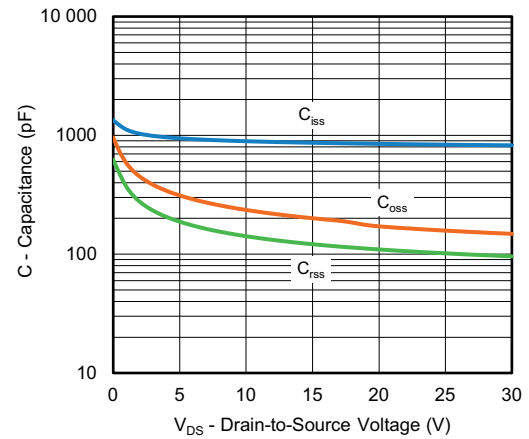
Transfer Characteristics



Transconductance



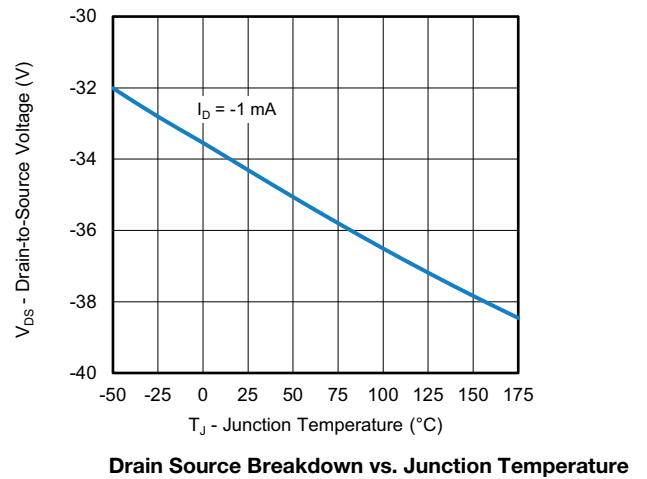
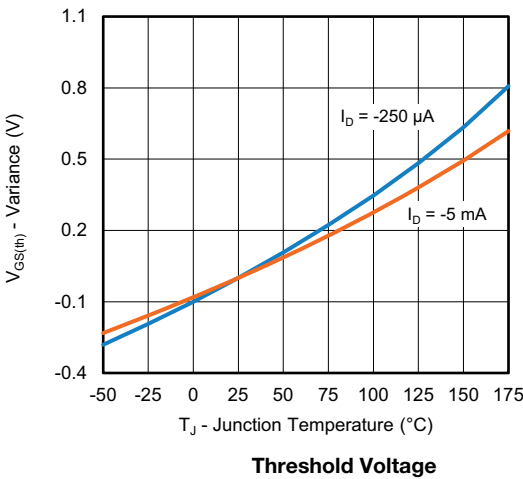
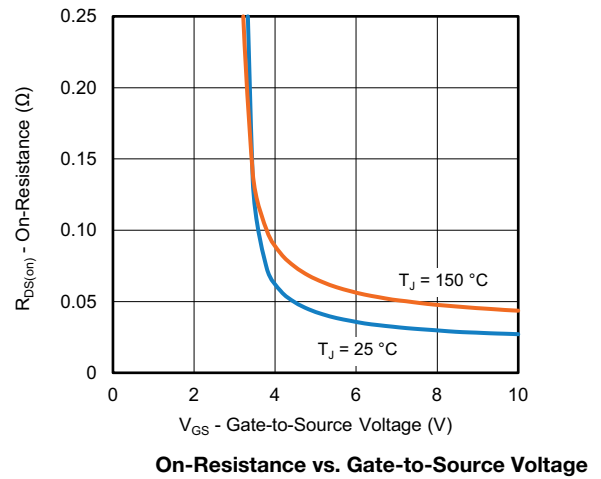
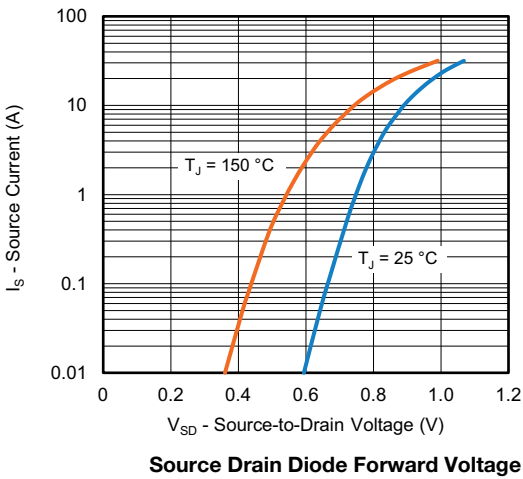
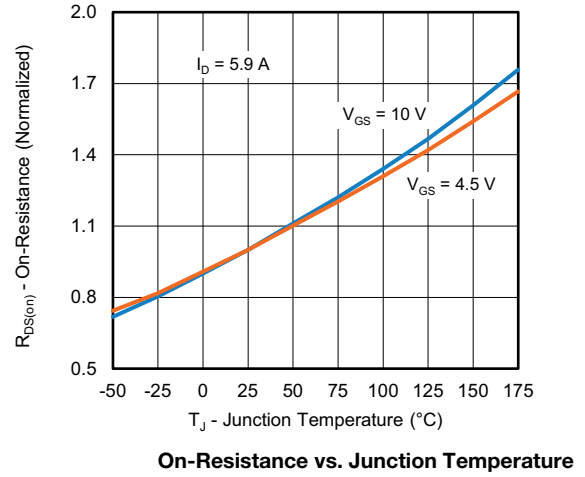
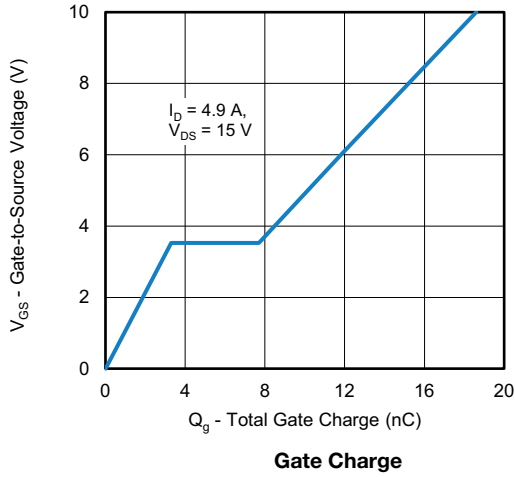
On-Resistance vs. Drain Current



Capacitance

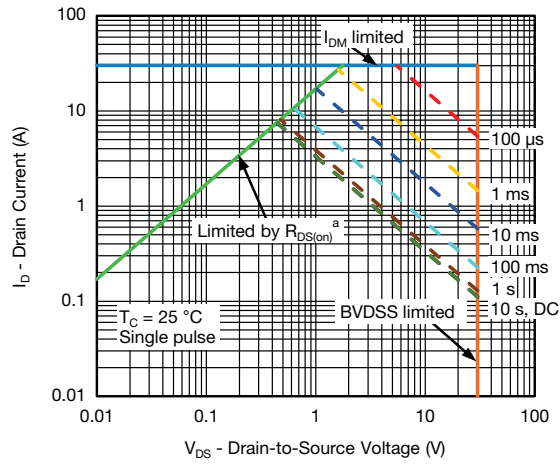


TYPICAL CHARACTERISTICS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)





THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



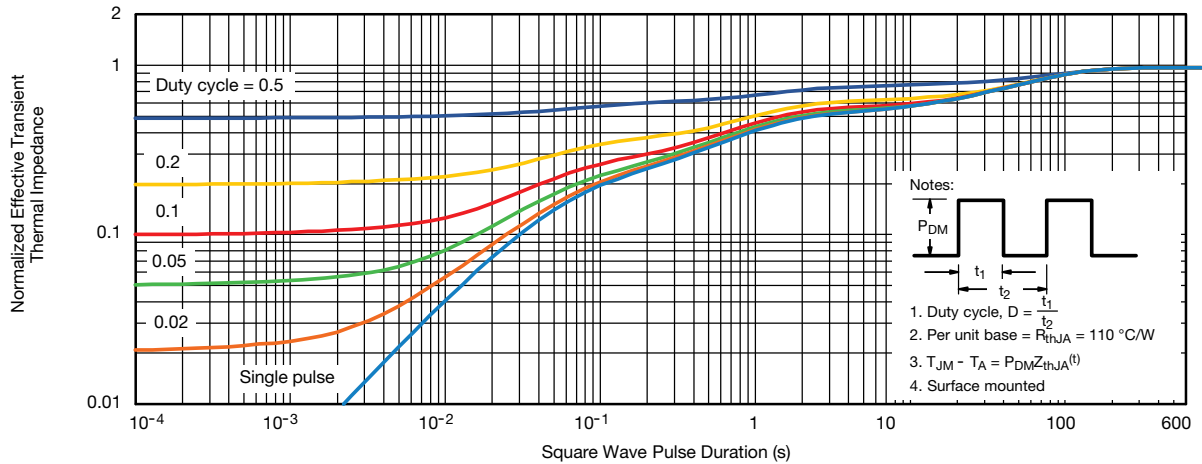
Safe Operating Area

Note

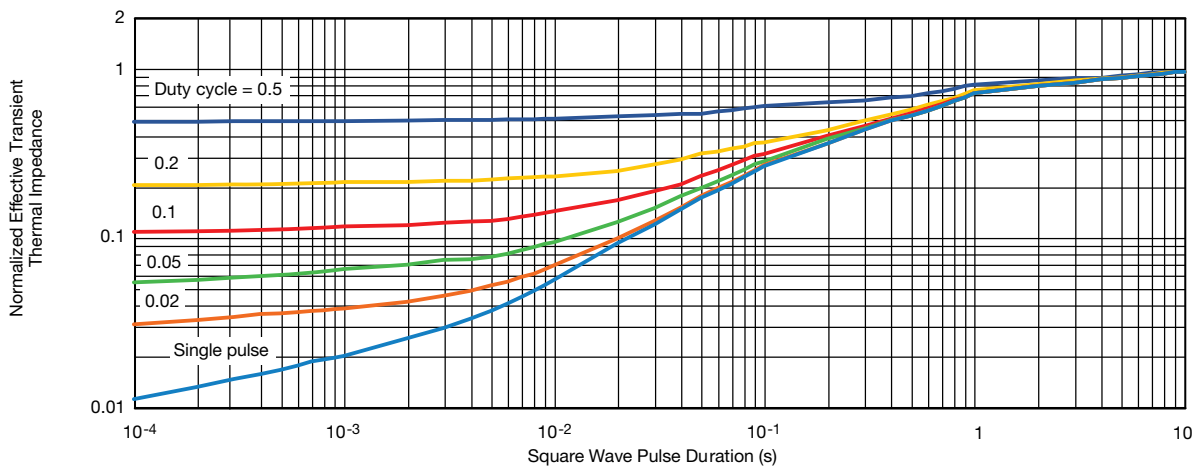
a. $V_{GS} >$ minimum V_{GS} at which $R_{DS(on)}$ is specified



THERMAL RATINGS ($T_A = 25\text{ }^\circ\text{C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient ($25\text{ }^\circ\text{C}$)
 - Normalized Transient Thermal Impedance Junction-to-Foot ($25\text{ }^\circ\text{C}$)
- are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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Vishay Material Code	Customer Material	Location
SQ4949EY-T1_BE3	SLNSQ4949EY-T1-BE3	Ft Worth